

50MHz VCXO IC

■GENERAL DESCRIPTION

The NJU6343 is VCXO IC up to 50MHz, which consists of an oscillation amplifier, internal variable capacitor, divider, and 3-state output buffer. The pull range is $\pm 100\text{ppm}$ to use internal variable capacitor only, depend on the external crystal parameters.

The oscillation amplifier is realized very low standby current using NAND circuit.

The 3-state output buffer is C-MOS compatible and up to 30pF load.

■FEATURES

- Operating Voltage 3.0 to 3.6V
- Maximum Oscillation Frequency 50MHz
- Frequency Pulling Range $\pm 100\text{ppm}$
- Low Operating Current
- High Fan-out $I_{OH}/I_{OL}=6\text{mA}$ @3.3V
- Oscillation Stop and Output Stand-by Function
- 3-State Output Buffer
- Internal Variable Capacitor
- Package Outline Thin-Chip
- C-MOS Technology

■LINE-UP TABLE

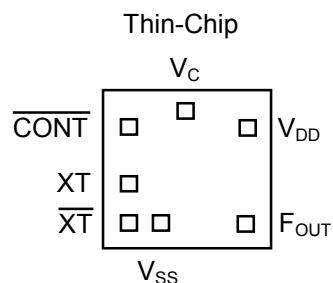
Type No.	F_{OUT}	Internal Connect	C_g/C_d
NJU6343 A	f_0	—	23/23pF

■PACKAGE OUTLINE



NJU6343AC-D

■PAD LOCATION



■PAD CONFIGURATION

No	Pad Name	X	Y
1	CONT	-400	215
2	XT	-400	-75
3	\overline{XT}	-400	-300
4	V_{SS}	-235	-300
5	F_{OUT}	400	-300
6	V_{DD}	400	200
7	V_C	-10	300

Starting Point:Chip Center Unit[um]

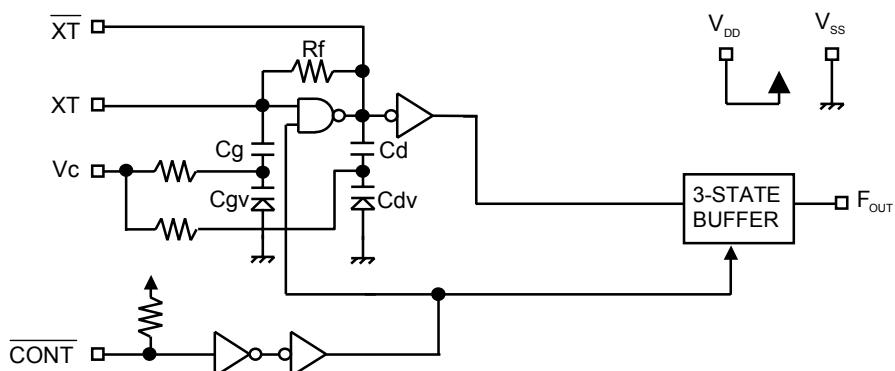
Chip Size:1.1x0.9mm

Thin-Chip Thickness(-D):200±20um

Pad Size:90x90um

Note1) Substrate: V_{DD} level

■BLOCK DIAGRAM



■ TERMINAL DESCRIPTION

SYMBOL	FUNCTION	
CONT	Oscillation and 3-state Output Buffer Control	
	CONT	F_{OUT}
	H or OPEN	Output frequency f_0
	L	Oscillation Stop and High impedance Output
XT	Quartz Crystal Connecting Terminals	
XT		
V_{SS}	$V_{SS}=0V$	
F_{OUT}	Frequency Output	
V_C	Frequency Control	
V_{DD}	$V_{DD}=3.3V$	

■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V_{DD}	-0.5 to +7.0	V
Input Voltage	V_{IN}	$V_{SS}-0.5$ to $V_{DD}+0.5$	V
Output Voltage	V_O	-0.5 to $V_{DD}+0.5$	V
Input Current	I_{IN}	± 10	mA
Output Current	I_O	± 25	mA
Operating Temperature Range	Topr	-40 to +85	°C
Storage Temperature Range	Tstg	-55 to +125	°C

Note2) If the supply voltage(V_{DD}) is less than 7.0V, the input voltage do not over the V_{DD} level.Note3) Decoupling capacitor should be connected between V_{DD} and V_{SS} due to the stabilized operation for the circuit.

■ ELECTRICAL CHARACTERISTICS

(Ta=25°C)

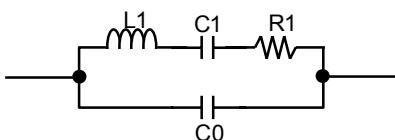
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Operating Voltage	V _{DD}		3.0	3.3	3.6	V

(V_{DD}=3.3V, V_C=V_{DD}/2, Ta=25°C)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Operating Current	I _{DD}	Type A, fosc=20MHz, C _L =15pF			5	mA
Oscillation Stopping Current	I _{STB}	CONT=V _{SS} , No load		2	5	uA
Stand-by Current	I _{st}	CONT=XT=V _{SS} , No load Note4)			1	uA
Input Voltage	V _{IH}		2.3		3.3	V
	V _{IL}		0		1.0	V
Output Current	I _{OH}	V _{OH} =2.97V	6			mA
	I _{OL}	V _{OL} =0.33V	6			mA
Input Current	I _{IN}	CONT=0.8V _{DD}		10	15	uA
		CONT=0.2V _{DD}		1.8	3.0	uA
Control Input Voltage	V _C		0		V _{DD}	V
Control Input Current	I _{VC}	V _C =0 to V _{DD}			±1	uA
3-state Off Leakage Current	I _{OZ}	CONT=V _{SS} , F _{OUT} =V _{DD} or V _{SS}			±0.1	uA
Feedback Resistance	R _f			255		kΩ
Internal Capacitor	C _{g/Cd}	fosc=20MHz		23/23		pF
	C _{gv/Cdv}	fosc=20MHz, V _C =0V Note5)		10/10		pF
		fosc=20MHz, V _C =V _{DD} Note5)		4/4		pF
Maximum Oscillation Frequency	F _{MAX}		50			MHz
Frequency Pulling Range	Δf/f ₀	V _C =0 to V _{DD}		±100		ppm
Frequency Linearity	Lin	V _C =0.1V _{DD} to 0.9V _{DD}		±10		%
Output Signal Symmetry	SYM	C _L =15pF, @V _{DD} /2	45	50	55	%
		C _L =30pF, @V _{DD} /2	45	50	55	
Output Signal Rise Time	tr	C _L =15pF, 0.1V _{DD} to 0.9V _{DD}		2.5	5.0	ns
		C _L =30pF, 0.1V _{DD} to 0.9V _{DD}		4.0	8.0	
Output Signal Fall Time	tf	C _L =15pF, 0.9V _{DD} to 0.1V _{DD}		2.5	5.0	ns
		C _L =30pF, 0.9V _{DD} to 0.1V _{DD}		4.0	8.0	
Output Disable time	t _{PLZ}	C _L =15pF, R _{UP} =10kΩ, V _C =0V			150	ns
Output Enable Time	t _{PZL}	C _L =15pF, R _{UP} =10kΩ, V _C =0V			150	ns
Oscillation Starting	t _{START}	C _L =15pF, Vtrigger=0.9V		1.5	10	ms

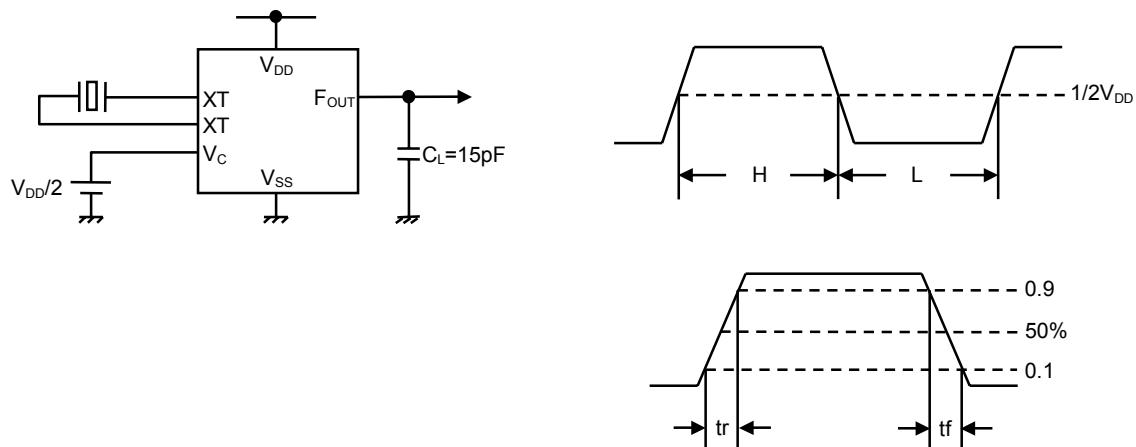
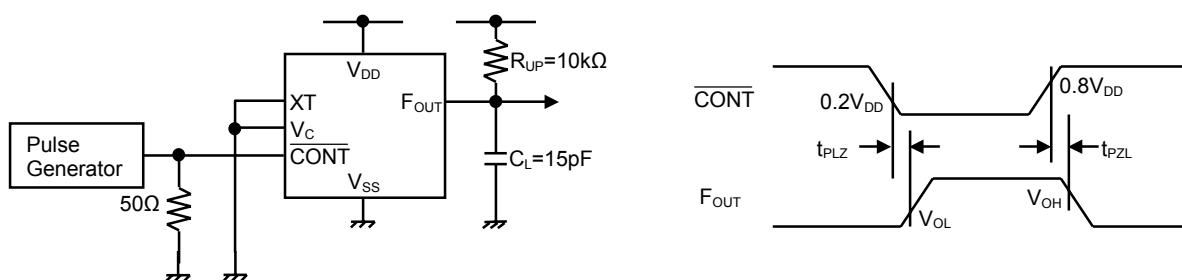
Note4) Excluding input current on CONT=V_{SS} Terminal.Note5) The C_{gv} and C_{dv} is design value.

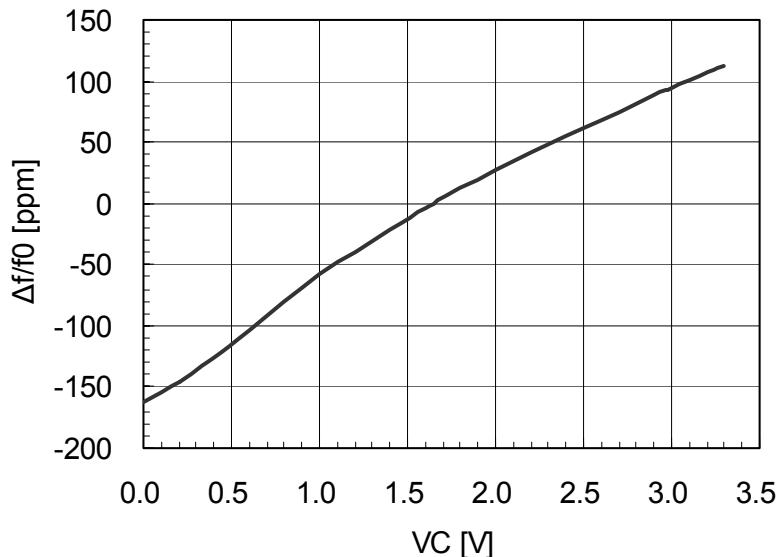
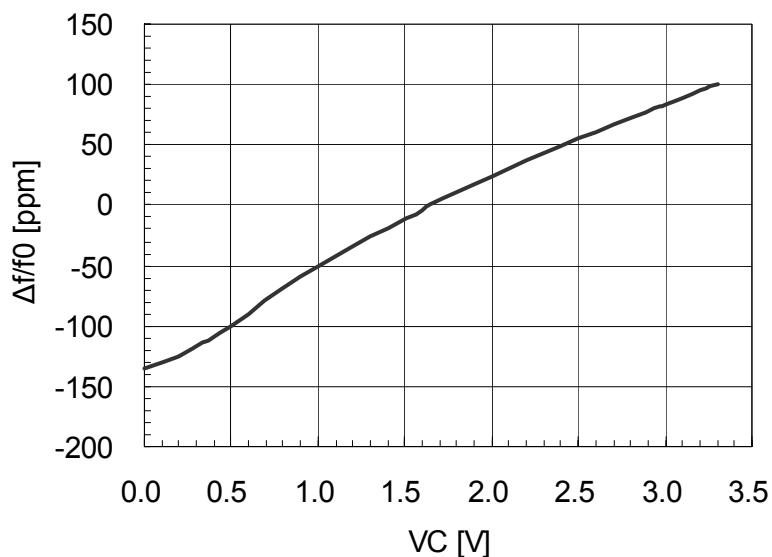
■ STANDARD CRYSTAL PARAMETERS FOR ELECTRICAL MEASUREMENTS



f[MHz]	R1[Ω]	L1[mH]	C1[fF]	C0[pF]	γ
20	16.9	4.7	13.6	3.1	227

■MEASUREMENT CIRCUITS

(1) Operating Current / Output Signal Symmetry / Output Signal Rise & Fall Time ($C_L=15\text{pF}$)(2) Output Disable & Enable Time ($C_L=15\text{pF}$, $R_{UP}=10\text{k}\Omega$, $V_C=0\text{V}$)

■TYPICAL CHARACTERISTICS(1)Frequency Pulling Range 1 ($V_{DD} = 3.3V$, $f_0 = 20MHz$, $R1 = 16.9\Omega$, $L1 = 4.7mH$, $C1 = 13.6fF$, $C0 = 3.1pF$, $\gamma = 227$)(2)Frequency Pulling Range 2 ($V_{DD} = 3.3V$, $f_0 = 21MHz$, $R1 = 13.1\Omega$, $L1 = 7.4mH$, $C1 = 7.8fF$, $C0 = 1.8pF$, $\gamma = 238$)

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